

## **PCI-4TE Series**

Features

Fast response

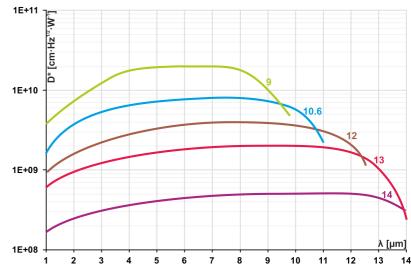
Low cost

Convenient to use

• Prompt delivery

## 2 – 14 µm IR PHOTOCONDUCTORS THERMOELECTRICALLY COOLED **OPTICALLY IMMERSED**





Example of D\* vs Wavelength \u03b3 for PCI-4TE Series HgCdTe Detectors. Spectral Characteristics of individual detectors may vary from those shown on the chart.

The PCI-4TE- $\lambda_{opt}$  photodetectors series ( $\lambda_{opt}$  - optimal wavelength in micrometers) feature IR photoconductive detector on four-stage thermoelectrical cooler, optically immersed to high refractive index GaAs hyperhemispherical (standard) or hemispherical or any intermediate lens (as option) for different acceptance angle and

The devices are optimized for the maximum performance at  $\lambda_{out}$ . Cut-on wavelength is limited by GaAs transmittance (~0.9 µm). Bias is needed to operate photocurrent. Performance at low frequencies (<20 kHz) is reduced due to 1/f noise. Highest performance and stability are achieved by application of variable gap (HgCd)Te semiconductor, optimized doping and sophisticated surface processing.

Custom devices with quadrant cells, multielement arrays, different windows, lenses and optical filters are available upon request.

Standard detectors are available in TO8 packages with wedged BaF<sub>2</sub> windows. Other packages, windows and connectors are also available.

## Parameter Symbol PCI-4TE-9 PCI-4TE-10.6 PCI-4TE-12 PCI-4TE-13 PCI-4TE-14 Unit **Optimal Wavelength**<sup>\*</sup> $\lambda_{opt}$ μm 9 10.6 12 13 14 Detectivity" cm·√Hz $@ \lambda_{\text{peak}}, 20 \text{ kHz}$ D\* ≥2.0×10<sup>10</sup> ≥8.0×10<sup>9</sup> ≥4.0×10<sup>9</sup> ≥2.0×10<sup>9</sup> ≥5.0×10<sup>8</sup> W @ λ<sub>opt</sub>, 20 kHz ≥1.0×10<sup>10</sup> ≥4.0×10<sup>9</sup> ≥2.0×10<sup>9</sup> ≥1.0×10<sup>9</sup> ≥3.0×10<sup>8</sup> Voltage Responsivity -V∙mm R.-w ≥200 ≥40 ≥15 ≥7 ≥5 Width Product @λ<sub>opt</sub> 1×1mm w **Time Constant** ≤8 ≤6 ≤5 ns ≤7 **Corner Frequency** 1/f kHz 1 to 20 l<sub>b</sub> mΑ **Bias Current - Width Ratio** 3 to 5 w mm Sheet Resistance **Ω/**□ 80 to 250 60 to 200 50 to 150 R<sub>sq</sub> **Operating Temperature** Т κ ~195 36, 1.62 Acceptance Angle, F/# Φ. deg, -

<sup>9</sup> Other Optimal Wavelengths available upon request.

IR Detector Specification @20°C

<sup>(7)</sup> Data Sheet states minimum guaranteed D\* values for each detector model. Higher performance detectors can be provided upon request.

| Туре         | Optical Area [mm×mm] |           |         |         |           |         |     |     |     |     |
|--------------|----------------------|-----------|---------|---------|-----------|---------|-----|-----|-----|-----|
|              | 0.025×0.025          | 0.05×0.05 | 0.1×0.1 | 0.2×0.2 | 0.25×0.25 | 0.5×0.5 | 1×1 | 2×2 | 3×3 | 4×4 |
| PCI-4TE-9    |                      |           |         |         | Х         | Х       | Х   | Х   | ĺ   |     |
| PCI-4TE-10.6 |                      |           |         |         | Х         | Х       | Х   | Х   |     |     |
| PCI-4TE-12   |                      |           |         |         | Х         | Х       | Х   | Х   |     |     |
| PCI-4TE-13   |                      |           |         |         | Х         | Х       | Х   | Х   |     |     |
| PCI-4TE-14   |                      |           |         |         | Х         | Х       | Х   | Х   |     |     |

X - standard detectors

## Description • High performance in the 2 to 14 µm spectral range • Wide dynamic range · Compact, rugged and reliable saturation level. Custom design upon request

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